
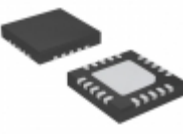
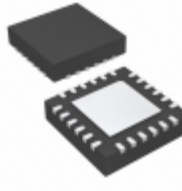





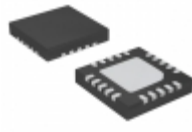
	<h2>SI3481DV-T1-E3</h2>
	<p><b>Hersteller-Teilenummer:</b> <a href="#">SI3481DV-T1-E3</a></p> <p><b>Hersteller / Marke:</b> <a href="#">Vishay / Siliconix</a></p> <p><b>Teil der Beschreibung:</b> MOSFET P-CH 30V 4A 6-TSOP</p> <p><b>Datenblätter:</b>  <a href="#">SI3481DV-T1-E3.pdf</a></p> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <p><b>Lagerzustand:</b> New original, 24152 pcs Stock Available.</p> <p><b>Liefern von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

### Spezifikationen

Teilenummer	<a href="#">SI3481DV-T1-E3</a>
Hersteller	<a href="#">Vishay / Siliconix</a>
Beschreibung	MOSFET P-CH 30V 4A 6-TSOP
Kategorie	<a href="#">Diskrete Halbleiterprodukte &gt; Transistoren-FETs,</a>
Teilstatus	24152 pcs Stock
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	SOT-23-6 Thin, TSOT-23-6
Supplier Device-Gehäuse	6-TSOP
Verlustleistung (max)	1.14W (Ta)
Typ FET	P-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	30V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	4A (Ta)
Rds On (Max) @ Id, Vgs	48 mOhm @ 5.3A, 10V
VGS (th) (Max) @ Id	3V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	25nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	-
Verpackung	Tape & Reel (TR)



























SI3481DV-T1-E3 ist neu im Original, Suche SI3481DV-T1-E3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI3481DV-T1-E3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SI3481DV-T1-E3: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <p><b>SI3480-A01-GMR</b> Energy Micro (Silicon Labs) IC CTRLR 4/8-PORT POE 20-QFN</p>	 <p><b>SI3482-A01-GM</b> Energy Micro (Silicon Labs) IC CTRLR POE 24-48PORT PSE 24-QFN</p>	 <p><b>SI3483-A02-GM</b> Energy Micro (Silicon Labs) IC POE PSE 64PORT 24QFN</p>	 <p><b>SI3477DV-T1-GE3</b> Electro-Films (EFI) / Vishay MOSFET P-CH 12V 8A 6-TSOP</p>
 <p><b>SI3481DV-T1-GE3</b> Vishay / Siliconix MOSFET P-CH 30V 4A 6-TSOP</p>	 <p><b>SI3481DV-T1-E3</b> Electro-Films (EFI) / Vishay MOSFET P-CH 30V 4A 6-TSOP</p>	 <p><b>SI3480MS8-KIT</b> Energy Micro (Silicon Labs) KIT EVAL 8PORT SI3480/52/SI3500</p>	 <p><b>SI3480-A01-GM</b> Energy Micro (Silicon Labs) IC CTRLR 4/8-PORT POE 20-QFN</p>

### heiße Teile

Mehr

 SI3469DV-T1-GE3	 SI3469DV-T1-GE3	 SI3471DV-T1-E3	 SI3473CDV-T1-E3	 SI3473CDV-T1-E3
 SI3473CDV-T1-GE3	 SI3473CDV-T1-GE3	 SI3473DDV-T1-GE3	 SI3473DV-T1-E3	 SI3473DV-T1-E3
 SI3473DV-T1-GE3	 SI3473DV-T1-GE3	 SI3474DV-T1-GE3	 SI3474DV-T1-GE3	 SI3475DV-T1-E3
 SI3475DV-T1-E3	 SI3475DV-T1-GE3	 SI3475DV-T1-GE3	 SI3476DV-T1-E3	 SI3476DV-T1-GE3
 SI3476DV-T1-GE3	 SI3477DV-T1-E3	 SI3477DV-T1-GE3	 SI3477DV-T1-GE3	 SI3481DV-T1-E3
 SI3481DV-T1-GE3	 SI3481DV-T1-GE3	 SI3483CDV-T1-E3	 SI3483CDV-T1-E3	 SI3483CDV-T1-GE3
 SI3483CDV-T1-GE3	 SI3483DV-T1-E3	 SI3483DV-T1-E3	 SI3483DV-T1-GE3	 SI3483DV-T1-GE3
 SI3493BDV-T1-E3	 SI3493BDV-T1-E3	 SI3493BDV-T1-E3-S	 SI3493BDV-T1-GE3	 SI3493BDV-T1-GE3
 SI3493DDV-T1-GE3	 SI3493DDV-T1-GE3	 SI3493DV	 SI3493DV-T1	 SI3493DV-T1-E3
 SI3493DV-T1-E3	 SI3493DV-T1-E3	 SI3493DV-T1-GE3	 SI3493DV-T1-GE3	 SI3495DV

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

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